LCD and Camera EMI Filter Array with ESD Protection

Features

- Six and eight channels of EMI filtering with integrated ESD protection
- Pi-style EMI filters in a capacitor-resistor-capacitor (C-R-C) network
- ±15kV ESD protection on each channel (IEC 61000-4-2 Level 4, contact discharge)
- ±30kV ESD protection on each channel (HBM)
- Greater than 35dB attenuation (typical) at 1 GHz
- TDFN package with 0.50mm lead pitch:
 - 6-ch. = 12-lead TDFN
 - 8-ch. = 16-lead TDFN
- Tiny TDFN package size:
 - 12-lead: 3.0mm x 1.35mm (two styles)
 - 16-lead: 4.0mm x 1.60mm
- Increased robustness against vertical impacts during manufacturing process
- Lead-free finishing

Applications

- LCD and Camera data lines in mobile handsets
- I/O port protection for mobile handsets, notebook computers, PDAs etc.
- EMI filtering for data ports in cell phones, PDAs or notebook computers.
- Wireless handsets
- Handheld PCs/PDAs
- LCD and camera modules

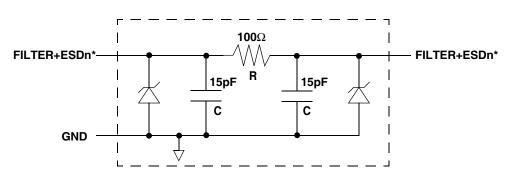
Electrical Schematic

Product Description

The CM1409 is a family of pi-style EMI filter arrays with ESD protection, which integrates six and eight filters (C-R-C) in small form factor TDFN 0.50mm pitch packages. The CM1409 has component values of 15pF- 100Ω -15pF per channel. The CM1409 has a cut-off frequency of 110MHz and can be used in applications with data rates up to 44Mbps. The parts include ESD diodes on every pin, which provide a very high level of protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). The ESD protection diodes safely dissipate ESD strikes of ±15kV, well beyond the maximum requirement of the IEC61000-4-2 international standard. Using the MIL-STD-883 (Method 3015) specification for Human Body Model (HBM) ESD, the pins are protected for contact discharges at greater than ±30kV.

These devices are particularly well-suited for portable electronics (e.g. wireless handsets, PDAs, notebook computers) because of their small package and easyto-use pin assignments. In particular, the CM1409 is ideal for EMI filtering and protecting data and control lines for the I/O data ports, LCD display and camera interface in mobile handsets.

The CM1409 is housed in space-saving, low-profile 12and 16-lead TDFN packages with a 0.50mm pitch and is available with lead-free finishing.



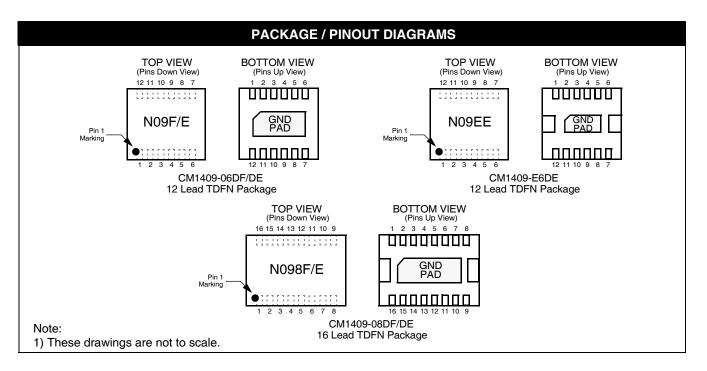
1 of 6 or 8 EMI/RFI + ESD Channels

* See Package/Pinout Diagram for expanded pin information.

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CM1409



	PIN DESCRIPTIONS									
DEVICE PIN(s)				DEVICE PIN(s)						
-06	-08	NAME	DESCRIPTION	-06	-08	NAME	DESCRIPTION			
1	1	FILTER1	Filter + ESD Channel 1	12	16	FILTER1	Filter + ESD Channel 1			
2	2	FILTER2	Filter + ESD Channel 2	11	15	FILTER2	Filter + ESD Channel 2			
3	3	FILTER3	Filter + ESD Channel 3	10	14	FILTER3	Filter + ESD Channel 3			
4	4	FILTER4	Filter + ESD Channel 4	9	13	FILTER4	Filter + ESD Channel 4			
5	5	FILTER5	Filter + ESD Channel 5	8	12	FILTER5	Filter + ESD Channel 5			
6	6	FILTER6	Filter + ESD Channel 6	7	11	FILTER6	Filter + ESD Channel 6			
	7	FILTER7	Filter + ESD Channel 7		10	FILTER7	Filter + ESD Channel 7			
	8	FILTER8	Filter + ESD Channel 8		9	FILTER8	Filter + ESD Channel 8			
GNE) PAD	GND	Device Ground							

Ordering Information

PART NUMBERING INFORMATION								
		Standard Finish Lead-free Finish						
		Ordering Part		Ordering Part				
Pins	Package	Number ¹	Part Marking	Number ¹	Part Marking			
12	TDFN-12	-	-	CM1409-E6DE	N09EE			
12	TDFN-12	CM1409-06DF	N09F	CM1409-06DE	N09E			
16	TDFN-16	CM1409-08DF	N098F	CM1409-08DE	N098E			

Note 1: Parts are shipped in Tape & Reel form unless otherwise specified.

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Specifications

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	RATING	UNITS				
Storage Temperature Range	-65 to +150	°C				
DC Power per Resistor	100	mW				
DC Package Power Rating	500	mW				

STANDARD OPERATING CONDITIONS						
PARAMETER	RATING	UNITS				
Operating Temperature Range	-40 to +85	°C				

	ELECTRICAL OPERATING CHARACTERISTICS (SEE NOTE1)									
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS				
R	Resistance		80	100	120	Ω				
C _{TOTAL}	Total Channel Capacitance	At 2.5VDC Reverse Bias, 1MHz, 30mVAC	24	30	36	pF				
С	Capacitance C ₁	At 2.5VDC Reverse Bias, 1MHz, 30mVAC	12	15	18	pF				
V _{DIODE}	Standoff Voltage	I _{DIODE} =10μA		6.0		V				
I _{LEAK}	Diode Leakage Current (reverse bias)	V _{DIODE} =+3.3V		0.1	1.0	μA				
V _{SIG}	Signal Clamp Voltage Positive Clamp Negative Clamp	I _{LOAD} = 10mA I _{LOAD} = -10mA	5.6 -1.5	6.8 -0.8	9.0 -0.4	v v				
V _{ESD}	In-system ESD Withstand Voltage a) Human Body Model, MIL-STD-883, Method 3015 b) Contact Discharge per IEC 61000-4- 2 Level 4	Notes 2 and 3	±30 ±15			kV kV				
R _{DYN}	Dynamic Resistance Positive Negative			2.3 0.9		Ω Ω				
f _c	Cut-off Frequency Z_{SOURCE} =50 Ω , Z_{LOAD} =50 Ω	Channel R = 100Ω Channel C = 15pF		110		MHz				
A _{1GHz}	Absolute Attenuation @ 1GHz from 0dB Level	$Z_{SOURCE} = 50\Omega$, $Z_{LOAD} = 50\Omega$, DC Bias = 0V; Notes 1, 4 and 5		35		dB				
A _{800MHz} - 6GHz	Absolute Attenuation @ 800MHz to 6GHz from 0dB Level	$Z_{SOURCE} = 50\Omega$, $Z_{LOAD} = 50\Omega$, DC Bias = 0V; Notes 1, 4 and 5		30		dB				

Note 1: $T_A=25^{\circ}C$ unless otherwise specified.

Note 2: ESD applied to input and output pins with respect to GND, one at a time.

Note 3: These parameters are guaranteed by design and characterization.

Note 4: Attenuation / RF curves characterized by a network analyzer using microprobes.

Note 5: These parameters are NOT guaranteed by design, characterization and production.

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Performance Information

Typical EMI Filter Performance (T_A=25°C, DC Bias=0V, 50 Ohm Environment)

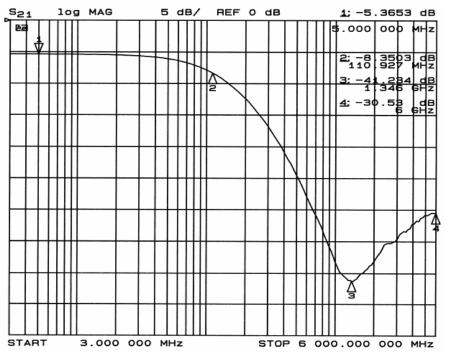
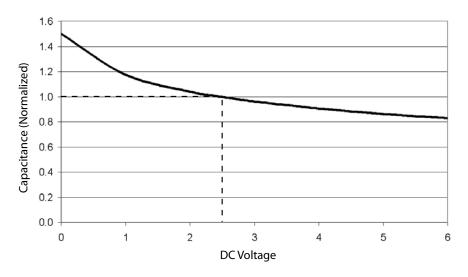
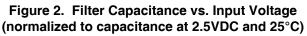


Figure 1. Insertion Loss vs. Frequency (Filter Input to GND)

Typical Diode Capacitance vs. Input Voltage





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Mechanical Details

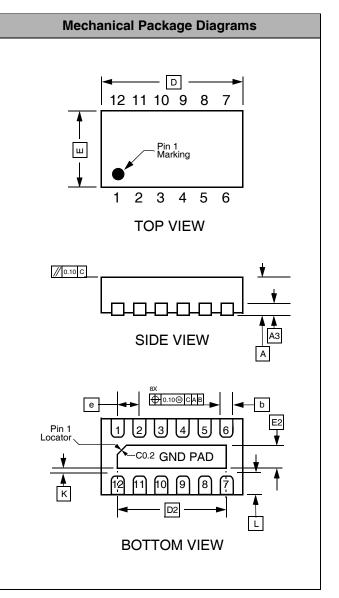
TDFN-12 Mechanical Specifications

The CM1409-06DF/DE is supplied in an 12-lead, 0.5mm pitch TDFN package. Dimensions are presented below.

For complete information on the TDFN-12, see the California Micro Devices TDFN Package Information document.

PACKAGE DIMENSIONS								
Package	TDFN							
JEDEC No.	MO-229C [†]							
Leads			1	2				
Dim.	N	lillimete	rs		Inches			
Dini.	Min	Nom	Max	Min	Nom	Max		
Α	0.70	0.75	0.80	0.028	0.030	0.031		
A3		0.20 RE	F	C).008 RE	F		
b	0.20	0.25	0.30	0.008	0.010	0.012		
D	2.90	3.00	3.10	0.114	0.118	0.122		
D2	2.40	2.50	2.60	0.095 0.098 0		0.102		
E	1.25	1.35	1.45	0.049	0.053	0.057		
E2	0.35	0.40	0.45	0.014	0.016	0.018		
е	(0.50 BS(0	C	.020 BS	C		
К	0.20			0.008				
L	0.20	0.25	0.30	0.008	0.010	0.012		
# per tape and reel	3000 pieces							
	Controlling dimension: millimeters							

[†]This package is compliant with JEDEC standard MO-229C with the exception of the "D", "D2", "E", "E2", "K" and "L" dimensions as called out in the table above.



Dimensions for 12-Lead, 0.5mm pitch TDFN package

Mechanical Details (cont'd)

TDFN-12 Mechanical Specifications

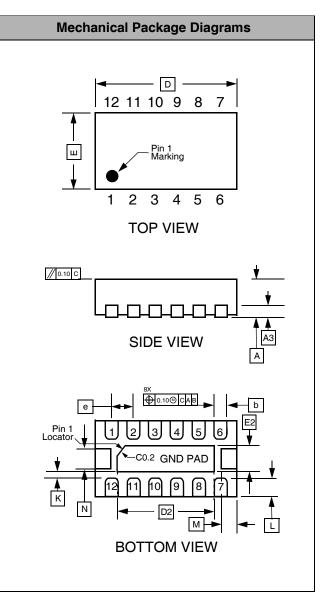
<u>__</u>V

The CM1409-E6DE is supplied in an 12-lead, 0.5mm pitch TDFN package. Dimensions are presented below.

For complete information on the TDFN-12, see the California Micro Devices TDFN Package Information document.

PACKAGE DIMENSIONS								
Package	TDFN							
JEDEC No.	MO-229C [†]							
Leads			1	12				
Dim.	N	lillimete	rs		Inches	ches		
Dini.	Min	Nom	Max	Min	Nom	Max		
Α	0.70	0.75	0.80	0.028	0.030	0.031		
A3		0.20 RE	F	C	.008 RE	F		
b	0.20	0.25	0.30	0.008 0.010 0.01				
D	2.90	3.00	3.10	0.114 0.118 0.1		0.122		
D2	2.10	2.20	2.30	0.083 0.087 0.0		0.091		
E	1.25	1.35	1.45	0.049 0.053 0.0		0.057		
E2	0.25	0.30	0.35	0.008	0.012	0.014		
е		0.50 BS	С	C	.020 BS	С		
К	0.20			0.008				
L	0.20	0.25	0.30	0.008	0.010	0.012		
М		0.20 REF 0.008 REF						
N	0.25 REF 0.010 REF					F		
# per tape and	3000 pieces							
reel								
	Controlling dimension: millimeters							

[†]This package is compliant with JEDEC standard MO-229C with the exception of the "D", "D2", "E", "E2", "K" and "L" dimensions as called out in the table above.



Dimensions for 12-Lead, 0.5mm pitch TDFN package

Cirtek POD-CEC-DFN12-015 3.00x1.35mm, 0.5mm pitch 12L TDFN

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Mechanical Details (cont'd)

TDFN-16 Mechanical Specifications

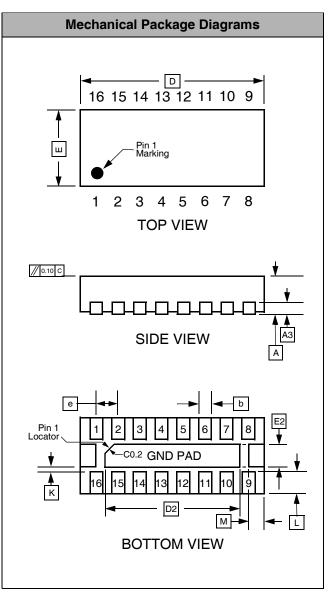
<u>__</u>V

The CM1409-08DE/DF is supplied in an 16-lead, 0.5mm pitch TDFN package. Dimensions are presented below.

For complete information on the TDFN-16, see the California Micro Devices TDFN Package Information document.

PACKAGE DIMENSIONS								
Package	TDFN							
JEDEC No.		MO-229C [†]						
Leads			1	16				
Dim.	N	lillimete	rs		Inches			
Dini.	Min	Nom	Max	Min	Nom	Max		
Α	0.70	0.75	0.80	0.028	0.030	0.031		
A3		0.20 RE	F	C	.008 RE	F		
b	0.20	0.25	0.30	0.008	0.010	0.012		
D	3.90	4.00	4.10	0.153	0.157	0.161		
D2	3.10	3.20	3.30	0.122	0.126	0.130		
E	1.50	1.60	1.70	0.059 0.063 0.06		0.067		
E2	0.30	0.40	0.50	0.012	0.016	0.020		
е		0.50 BS	С	().020 BS	SC		
К	0.20			0.008				
L	0.20	0.30	0.40	0.008	0.010	0.012		
М	0.25 REF 0.010 REF							
# per tape and	3000 pieces							
reel								
Controlling dimension: millimeters								

[†]This package is compliant with JEDEC standard MO-229C with the exception of the "D", "D2", "E", "E2", "K" and "L" dimensions as called out in the table above.



Dimensions for 16-Lead, 0.5mm pitch TDFN package

Cirtek POD-CEC-DFN16-013 4.00x1.60mm, 0.5mm pitch 16L TDFN

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